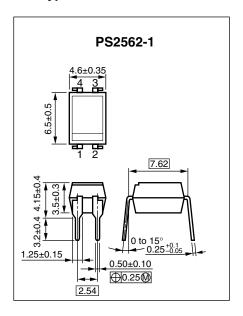
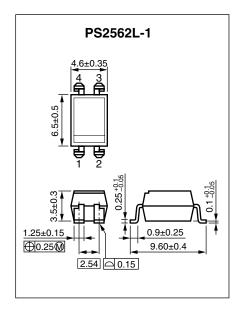
<R> PACKAGE DIMENSIONS (UNIT: mm)

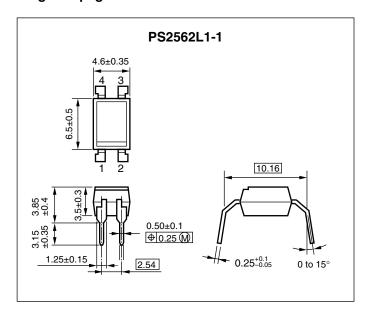
DIP Type



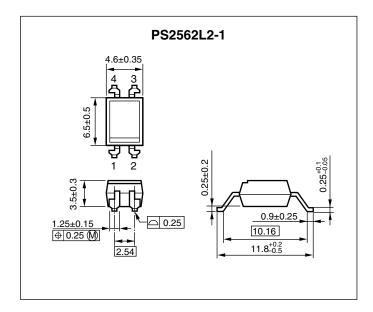
Lead Bending Type (Gull-Wing)



Long Creepage Distance



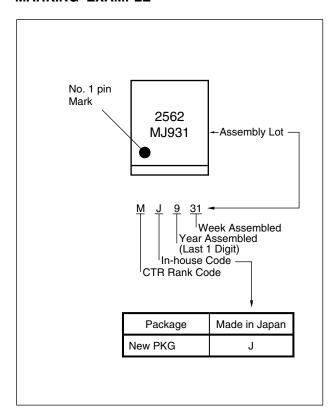
Long Creepage Distance (Gull-Wing)



<R> PHOTOCOUPLER CONSTRUCTION

Parameter	Unit (MIN.)
Air Distance	7 mm
Outer Creepage Distance	7 mm
Inner Creepage Distance	4 mm
Isolation Thickness	0.4 mm

<R> MARKING EXAMPLE



<R> ORDERING INFORMATION

Part Number	Order Number	Solder Plating Specification	Packing Style	Safety Standard Approval	Application Part Number ^{⁴1}
PS2562-1	PS2562-1-A	Pb-Free	Magazine case 100 pcs	Standard products	PS2562-1
PS2562L-1	PS2562L-1-A			(UL, CSA, BSI,	
PS2562L1-1	PS2562L1-1-A			SEMKO, NEMKO,	
PS2562L2-1	PS2562L2-1-A			DEMKO, FIMKO	
PS2562L-1-F3	PS2562L-1-F3-A		Embossed Tape 2 000 pcs/reel	approved)	
PS2562L2-1-E3	PS2562L2-1-E3-A		Embossed Tape 1 000 pcs/reel		
PS2562-1-V	PS2562-1-V-A		Magazine case 100 pcs	DIN EN60747-5-2	
PS2562L-1-V	PS2562L-1-V-A			(VDE0884 Part2)	
PS2562L1-1-V	PS2562L1-1-V-A			approved products	
PS2562L2-1-V	PS2562L2-1-V-A			(option)	
PS2562L-1-V-F3	PS2562L-1-V-F3-A		Embossed Tape 2 000 pcs/reel		
PS2562L2-1-V-E3	PS2562L2-1-V-E3-A		Embossed Tape 1 000 pcs/reel		

^{*1} For the application of the Safety Standard, following part number should be used.

ABSOLUTE MAXIMUM RATINGS (TA = 25°C, unless otherwise specified)

Parameter		Symbol	Ratings	Unit
Diode	Reverse Voltage	VR	6	V
	Forward Current (DC)	lF	80	mA
	Power Dissipation Derating	⊿P₀/°C	1.5	mW/°C
	Power Dissipation	Po	150	mW
	Peak Forward Current [™]	IFP	1	Α
Transistor	Collector to Emitter Voltage	VCEO	40	٧
	Emitter to Collector Voltage	VECO	6	٧
	Collector Current	lc	200	mA
	Power Dissipation Derating	⊿Pc/°C	2.0	mW/°C
	Power Dissipation	Pc	200	mW
Isolation Voltage ²		BV	5 000	Vr.m.s.
Operating Ambient Temperature		TA	-55 to +100	°C
Storage Temperature		T _{stg}	-55 to +150	°C

^{*1} PW = 100 μ s, Duty Cycle = 1%

^{*2} AC voltage for 1 minute at T_A = 25°C, RH = 60% between input and output. Pins 1-2 shorted together, 3-4 shorted together.

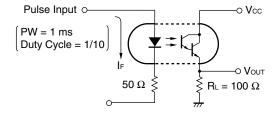
ELECTRICAL CHARACTERISTICS (TA = 25°C)

	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	VF	IF = 10 mA		1.17	1.4	V
	Reverse Current	lR	V _R = 5 V			5	μΑ
	Terminal Capacitance	Ct	V = 0 V, f = 1.0 MHz		50		pF
Transistor	Collector to Emitter Dark Current	Iceo	VcE = 40 V, IF = 0 mA			400	nA
Coupled	Current Transfer Ratio	CTR	IF = 1 mA, VCE = 2 VDC	200	2 000		%
	Collector Saturation Voltage	VCE (sat)	IF = 1 mA, Ic = 2 mA			1.0	V
	Isolation Resistance	R _{I-O}	Vi-o = 1.0 kVDC	10 ¹¹			Ω
	Isolation Capacitance	C _{I-O}	V = 0 V, f = 1.0 MHz		0.5		pF
	Rise Time ¹²	t r	Vcc = 10 V, Ic = 10 mA, R _L = 100 Ω		100		μs
	Fall Time'2	tf			100		

*1 CTR rank

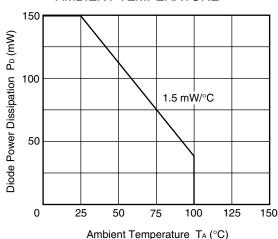
K : 2 000 to (%) L : 700 to 3 400 (%) M : 200 to 1 000 (%)

*2 Test circuit for switching time

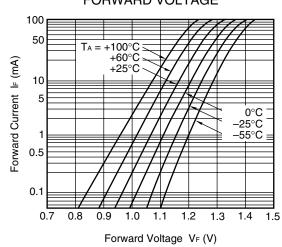


TYPICAL CHARACTERISTICS (TA = 25°C, unless otherwise specified)

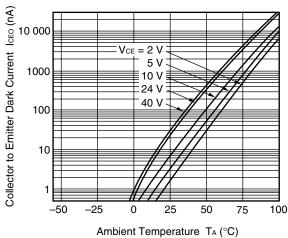




FORWARD CURRENT vs. FORWARD VOLTAGE

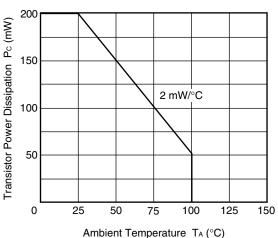


COLLECTOR TO EMITTER DARK CURRENT vs. AMBIENT TEMPERATURE

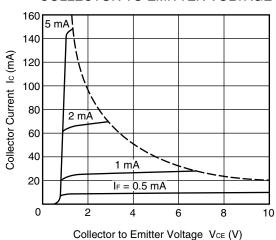


Remark The graphs indicate nominal characteristics.

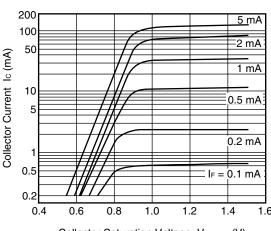
TRANSISTOR POWER DISSIPATION vs. AMBIENT TEMPERATURE



COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE

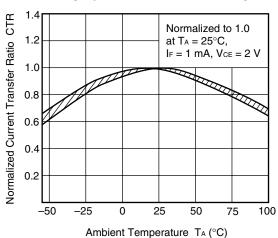


COLLECTOR CURRENT vs. COLLECTOR SATURATION VOLTAGE

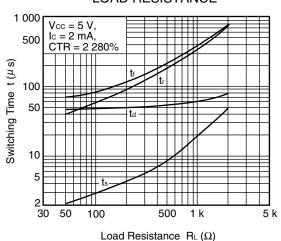


Collector Saturation Voltage VCE (sat) (V)

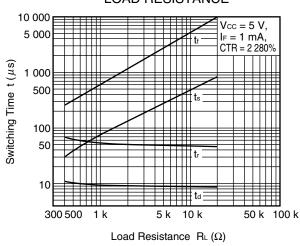
NORMALIZED CURRENT TRANSFER RATIO vs. AMBIENT TEMPERATURE



SWITCHING TIME vs. LOAD RESISTANCE

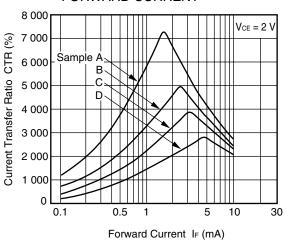


SWITCHING TIME vs. LOAD RESISTANCE

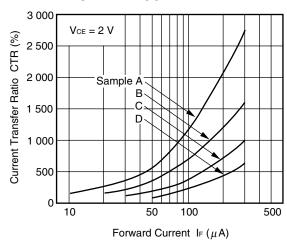


Remark The graphs indicate nominal characteristics.

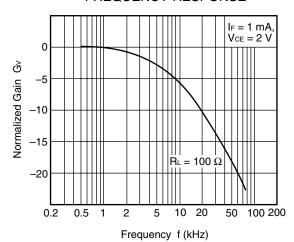
CURRENT TRANSFER RATIO vs. FORWARD CURRENT



CURRENT TRANSFER RATIO vs. FORWARD CURRENT



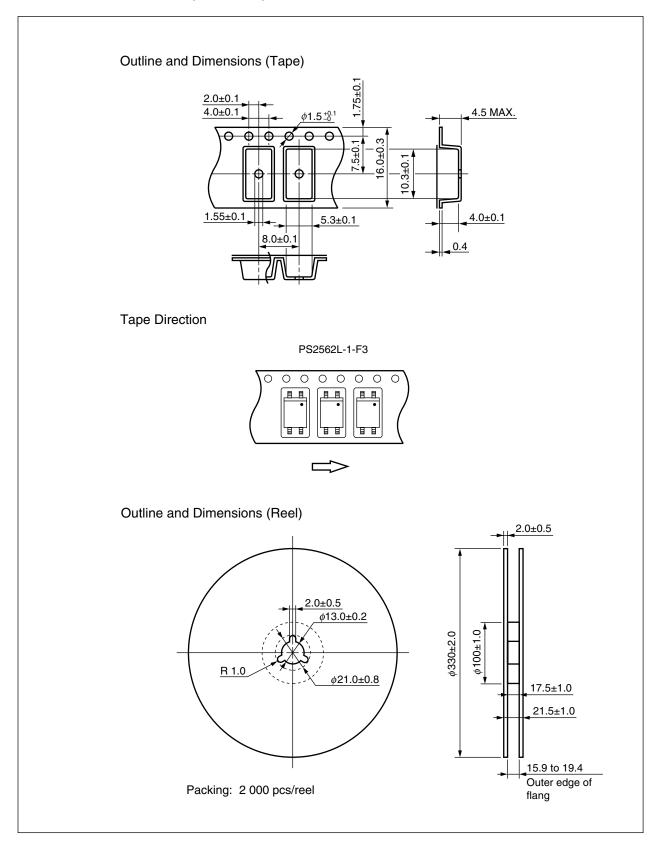
FREQUENCY RESPONSE

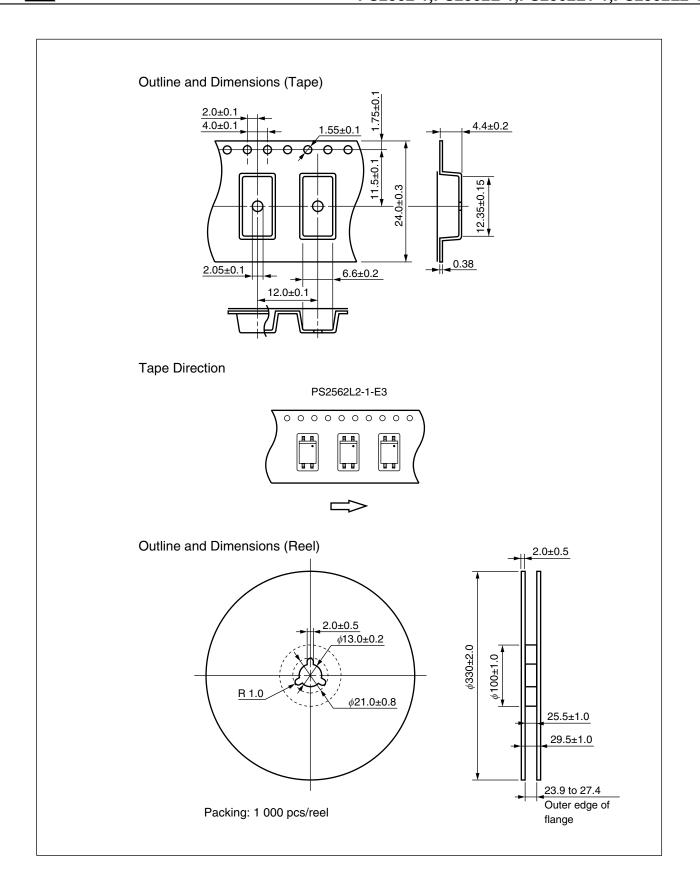


LONG TERM CTR DEGRADATION 1.2 $I_F = 1 \text{ mA}$ 1.0 CTR (Relative Value) T_A = 25°C 8.0 T_A = 60°C 0.6 0.4 0.2 10⁴ 10⁵ 10² 10³ 10⁶ 10 Time (Hr)

Remark The graph indicates nominal characteristics.

<R> TAPING SPECIFICATIONS (UNIT : mm)





NOTES ON HANDLING

1. Recommended soldering conditions

(1) Infrared reflow soldering

· Peak reflow temperature 260°C or below (package surface temperature)

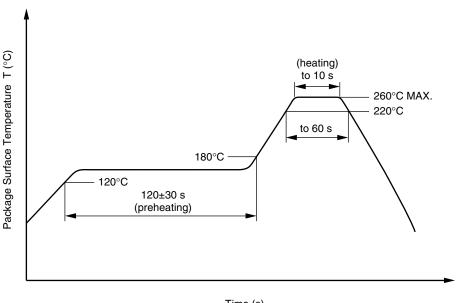
• Time of peak reflow temperature 10 seconds or less • Time of temperature higher than 220°C 60 seconds or less

• Time to preheat temperature from 120 to 180°C 120±30 s Number of reflows Three

• Flux Rosin flux containing small amount of chlorine (The flux with a

maximum chlorine content of 0.2 Wt% is recommended.)

Recommended Temperature Profile of Infrared Reflow



Time (s)

(2) Wave soldering

 Temperature 260°C or below (molten solder temperature)

• Time 10 seconds or less

· Preheating conditions 120°C or below (package surface temperature)

· Number of times One (Allowed to be dipped in solder including plastic mold portion.)

• Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine

content of 0.2 Wt% is recommended.)

(3) Soldering by soldering iron

• Peak temperature (lead part temperature) 350°C or below • Time (each pins) 3 seconds or less

Flux Rosin flux containing small amount of chlorine (The flux with a

maximum chlorine content of 0.2 Wt% is recommended.)

(a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead.

(b) Please be sure that the temperature of the package would not be heated over 100°C.

(4) Cautions

Fluxes

Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output or between collector-emitters at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.

3. Measurement conditions of current transfer ratios (CTR), which differ according to photocoupler

Check the setting values before use, since the forward current conditions at CTR measurement differ according to product.

When using products other than at the specified forward current, the characteristics curves may differ from the standard curves due to CTR value variations or the like. Therefore, check the characteristics under the actual operating conditions and thoroughly take variations or the like into consideration before use.

USAGE CAUTIONS

- 1. Protect against static electricity when handling.
- 2. Avoid storage at a high temperature and high humidity.

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<R> SPECIFICATION OF VDE MARKS LICENSE DOCUMENT

Parameter	Symbol	Speck	Unit
Climatic test class (IEC 60068-1/DIN EN 60068-1)		55/100/21	
Dielectric strength maximum operating isolation voltage Test voltage (partial discharge test procedure a for type test and random test) $U_{pr} = 1.5 \times U_{IORM}$, $P_d < 5 \ pC$	UIORM Upr	890 1 335	V _{peak} V _{peak}
Test voltage (partial discharge test procedure b for all devices test) $U_{pr}=1.875\times U_{\text{IORM}},P_{d}<5\;pC$	Upr	1 669	V _{peak}
Highest permissible overvoltage	UTR	8 000	V _{peak}
Degree of pollution (DIN EN 60664-1 VDE0110 Part 1)		2	
Comparative tracking index (IEC 60112/DIN EN 60112 (VDE 0303 Part 11))	СТІ	175	
Material group (DIN EN 60664-1 VDE0110 Part 1)		III a	
Storage temperature range	T _{stg}	-55 to +150	°C
Operating temperature range	TA	-55 to +100	°C
Isolation resistance, minimum value $V_{IO} = 500 \; V \; dc \; at \; T_A = 25 \; ^{\circ}C$ $V_{IO} = 500 \; V \; dc \; at \; T_A \; MAX. \; at \; least \; 100 \; ^{\circ}C$	Ris MIN. Ris MIN.	10 ¹² 10 ¹¹	Ω Ω
Safety maximum ratings (maximum permissible in case of fault, see thermal derating curve) Package temperature Current (input current I _F , Psi = 0) Power (output or total power dissipation) Isolation resistance	Tsi Isi Psi	175 400 700	°C mA mW
$V_{IO} = 500 \text{ V dc at T}_A = 175 ^{\circ}\text{C (Tsi)}$	Ris MIN.	10°	Ω

Caution

GaAs Products

This product uses gallium arsenide (GaAs).

GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.

- Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
- Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
- 2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
- Do not burn, destroy, cut, crush, or chemically dissolve the product.
- Do not lick the product or in any way allow it to enter the mouth.

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